

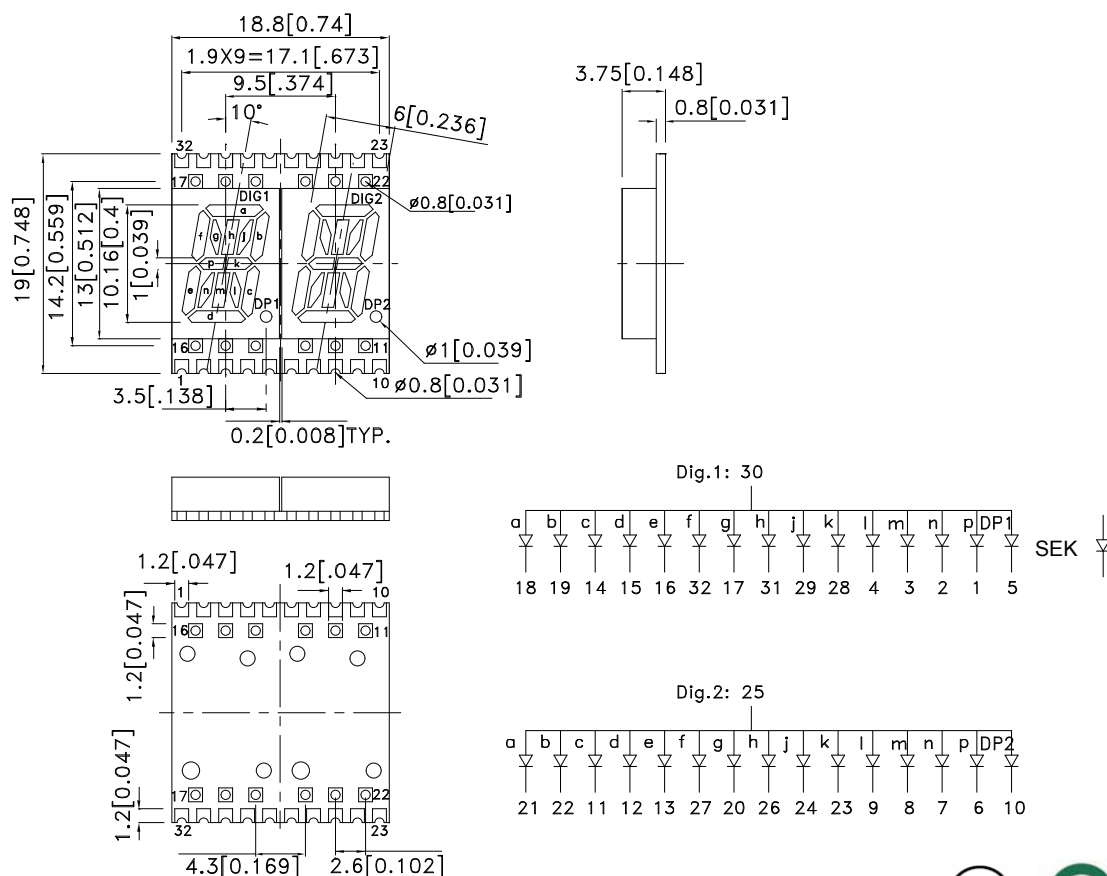
Features

- 0.4 inch character height.
- Low current operation.
- High contrast and light output.
- Categorized for luminous intensity.
- Mechanically rugged.
- Gray face, white segment.
- Package :250pcs / reel.
- Moisture sensitivity level : level 2a.
- Halogen Free.
- RoHS compliant.

Description

The Super Bright Orange device is made with AlGaInP (on GaAs substrate) light emitting diode chip.

Package Dimensions& Internal Circuit Diagram



Notes:

1. All dimensions are in millimeters (inches), Tolerance is $\pm 0.25(0.01)$ unless otherwise noted.
2. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.
3. The gap between the reflector and PCB shall not exceed 0.25mm.



Selection Guide

| Part No. | Dice | Lens Type | Iv (ucd) [1] @ 10mA | | Description |
|-------------|-------------------------------|----------------|------------------------|--------|------------------------------------|
| | | | Min. | Typ. | |
| KCPDA04-106 | Super Bright Orange (AlGaInP) | White Diffused | 21000 | 44000 | Common Anode, Rt. Hand Decimal. |
| | | | *5600 | *13000 | |

Notes:

1. Luminous intensity/ luminous Flux: +/-15%.

* Luminous intensity value is traceable to the CIE127-2007 compliant national standards.

Electrical / Optical Characteristics at TA=25°C

| Symbol | Parameter | Device | Typ. | Max. | Units | Test Conditions |
|-----------------------|--------------------------|---------------------|------|------|-------|---------------------------|
| λ_{peak} | Peak Wavelength | Super Bright Orange | 610 | | nm | I _F =20mA |
| λ_D [1] | Dominant Wavelength | Super Bright Orange | 601 | | nm | I _F =20mA |
| $\Delta\lambda_{1/2}$ | Spectral Line Half-width | Super Bright Orange | 29 | | nm | I _F =20mA |
| C | Capacitance | Super Bright Orange | 15 | | pF | V _F =0V;f=1MHz |
| V _F [2] | Forward Voltage | Super Bright Orange | 2.1 | 2.5 | V | I _F =20mA |
| I _R | Reverse Current | Super Bright Orange | | 10 | uA | V _R =5V |

Notes:

1.Wavelength: +/-1nm.

2.Forward Voltage: +/-0.1V.

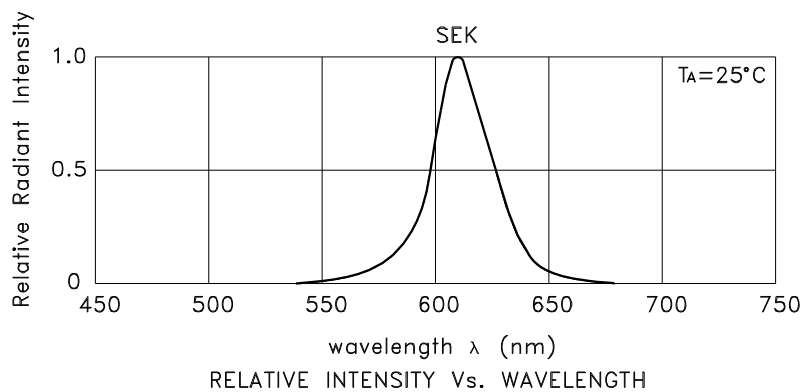
3.Wavelength value is traceable to the CIE127-2007 compliant national standards.

Absolute Maximum Ratings at TA=25°C

| Parameter | Super Bright Orange | Units |
|---------------------------------|---------------------|-------|
| Power dissipation | 75 | mW |
| DC Forward Current | 30 | mA |
| Peak Forward Current [1] | 195 | mA |
| Reverse Voltage | 5 | V |
| Operating / Storage Temperature | -40°C To +85°C | |

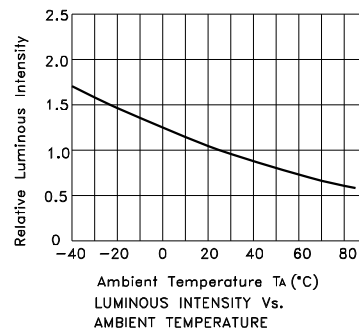
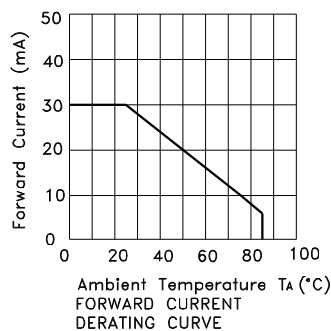
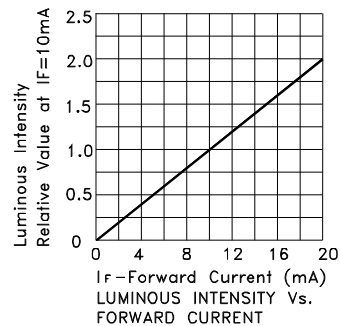
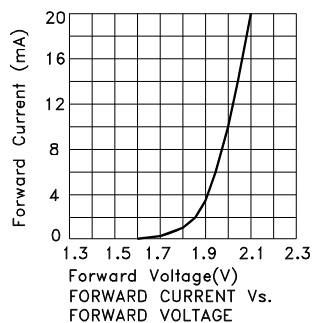
Note:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.



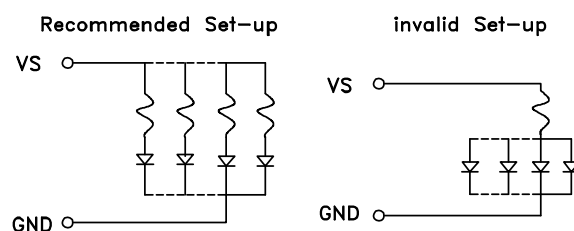
Super Bright Orange

KCPDA04-106



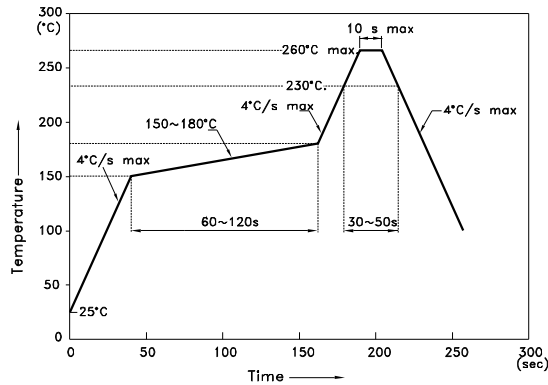
CIRCUIT DESIGN NOTES

1. Protective current-limiting resistors may be necessary to operate the Displays.
2. LEDs mounted in parallel should each be placed in series with its own current-limiting resistor.



KCPDA04-106

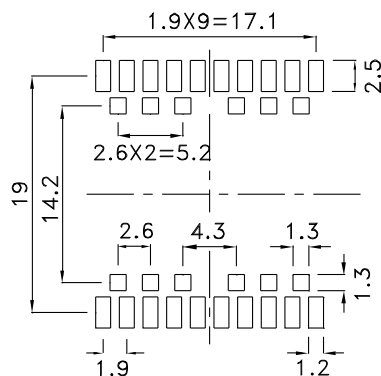
Reflow Soldering Profile For Lead-free SMT Process.



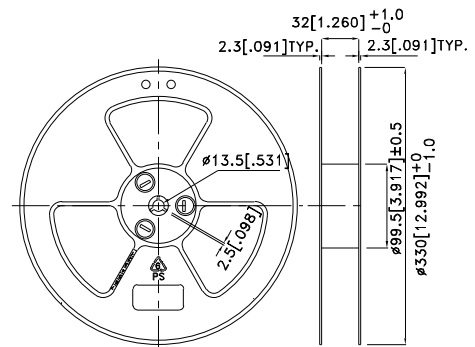
NOTES:

1. We recommend the reflow temperature 245°C(+/-5°C). The maximum soldering temperature should be limited to 260°C.
2. Don't cause stress to the epoxy resin while it is exposed to high temperature.
3. Number of reflow process shall be 2 times or less.

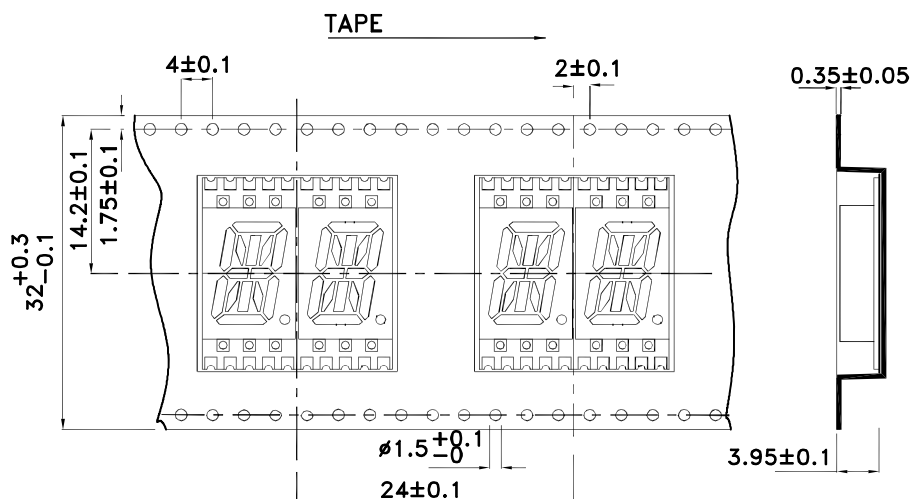
Recommended Soldering Pattern (Units : mm; Tolerance: ± 0.15)



Reel Dimension

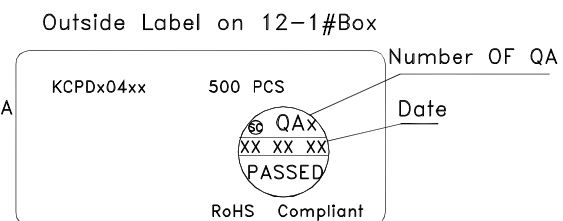
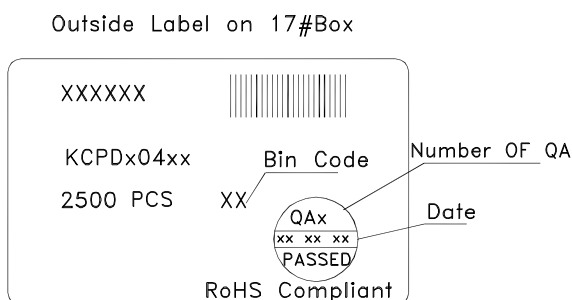
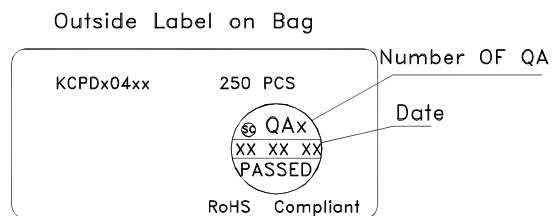
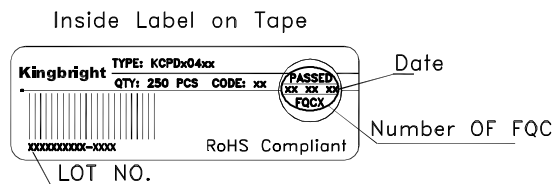
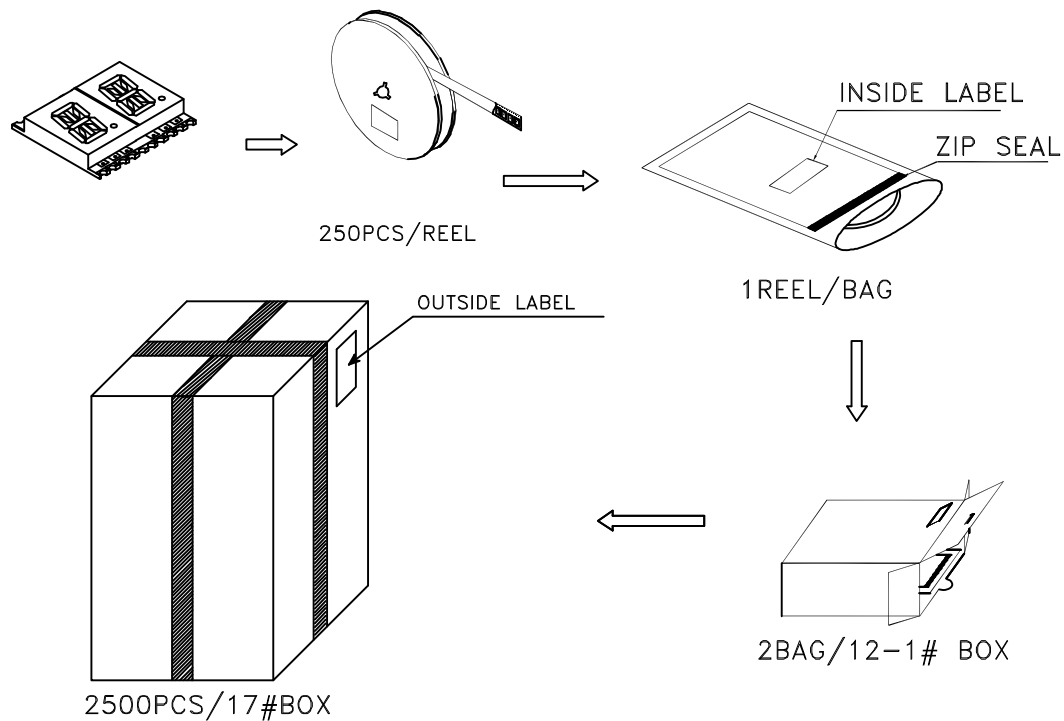


Tape Specifications (Units : mm)



PACKING & LABEL SPECIFICATIONS

KCPDA04-106



Detailed application notes are listed on our website.
http://www.kingbright.com/application_notes